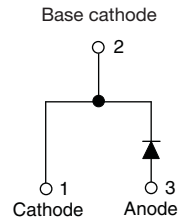
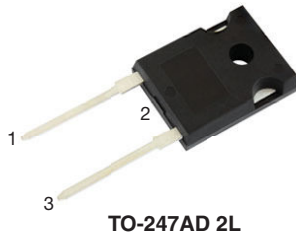


## Hyperfast Rectifier, 60 A FRED Pt<sup>®</sup> G5



### FEATURES

- Hyperfast and optimized  $Q_{rr}$
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	60 A
$V_R$	1200 V
$V_F$ at $I_F$ at 125 °C	1.7 V
$t_{rr}$	38 ns
$T_J$ max.	175 °C
Package	TO-247AD 2L
Circuit configuration	Single

### DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	$V_{RRM}$		1200	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 115\text{ °C}$ , $D = 0.50$	60	A
Non-repetitive peak surge current	$I_{FSM}$	$T_C = 45\text{ °C}$ , $t_p = 10\text{ ms}$ , sine wave	460	
Repetitive peak forward current	$I_{FRM}$	$T_C = 115\text{ °C}$ , $D = 0.50$ , $f = 20\text{ kHz}$	120	
Operating junction and storage temperature	$T_J$ , $T_{Stg}$		-55 to +175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_R$	$I_R = 100\text{ }\mu\text{A}$	1200	-	-	V
Forward voltage	$V_F$	$I_F = 60\text{ A}$	-	1.9	2.3	
		$I_F = 60\text{ A}$ , $T_J = 125\text{ °C}$	-	1.7	-	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	50	$\mu\text{A}$
		$T_J = 125\text{ °C}$ , $V_R = V_R$ rated	-	-	500	
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	-	32	-	pF
Series inductance	$L_S$	Measured to lead 5 mm from package body	-	8	-	nH

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}$ , $di_F/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	38	-	ns
		$T_J = 25\text{ }^\circ\text{C}$	-	130	-	
		$T_J = 125\text{ }^\circ\text{C}$	-	200	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	-	22	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	39	-	
		$I_F = 40\text{ A}$ $di_F/dt = 600\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	1610	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	4080	-	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	4080	-	
Reverse recovery time	$t_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	100	-	ns
		$T_J = 125\text{ }^\circ\text{C}$	-	153	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	-	40	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	67	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	2590	-	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	6150	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	$R_{thJC}$		-	-	0.4	$^\circ\text{C}/\text{W}$
Weight			-	5.5	-	g
			-	0.2	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^\circ\text{C}$
Marking device		Case style TO-247AD 2L	E5PH6012L			

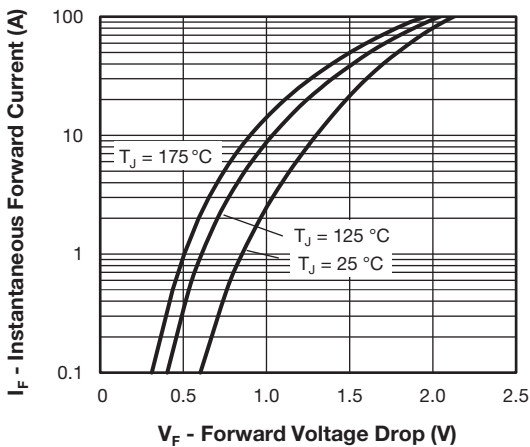


Fig. 1 - Typical Forward Voltage Drop Characteristics

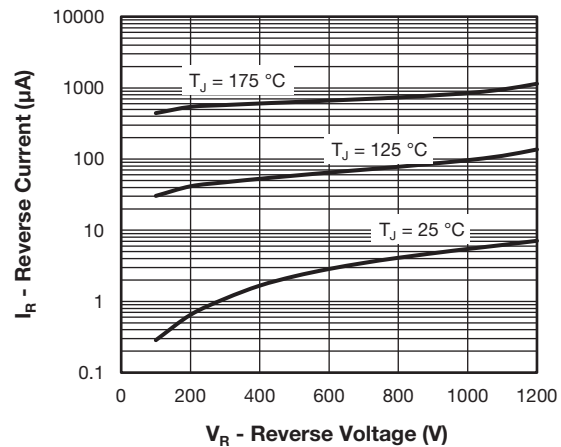


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

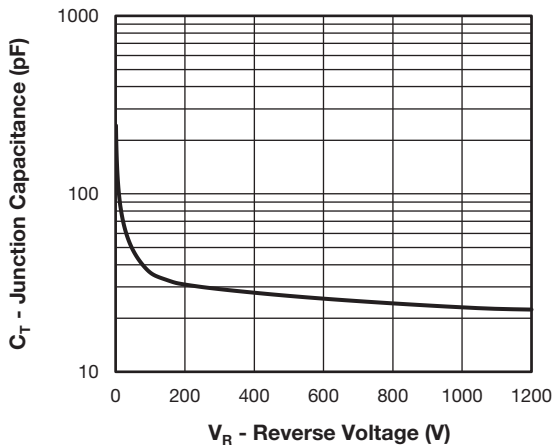


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

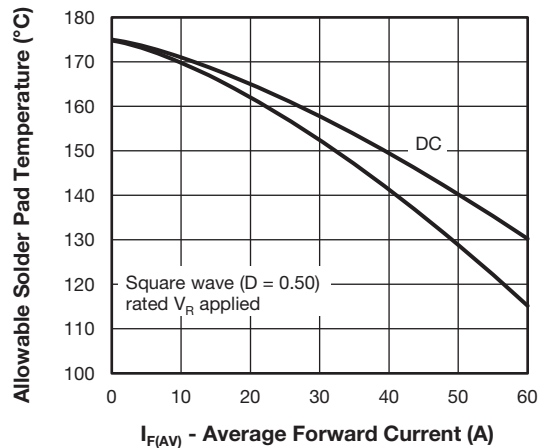


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

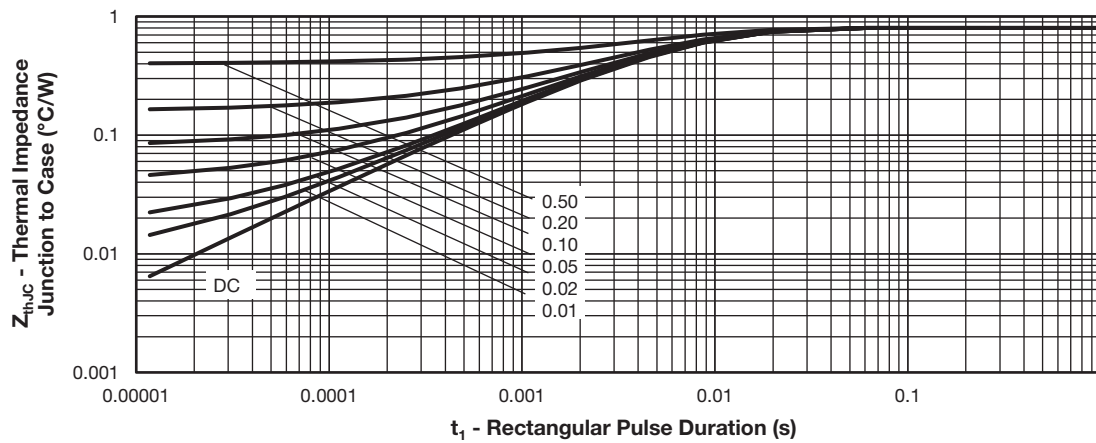


Fig. 5 - Thermal Impedance  $Z_{thJC}$  Characteristics

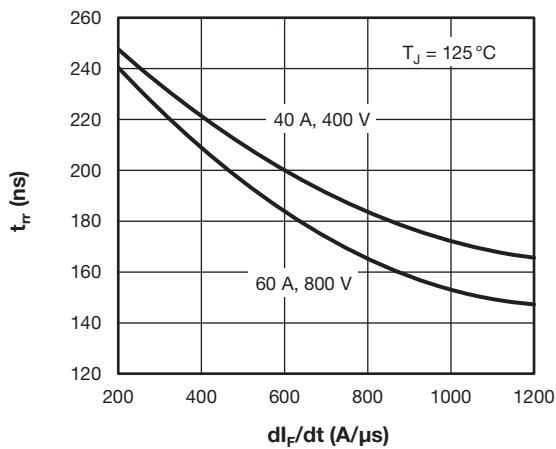


Fig. 6 - Typical Reverse Recovery Time vs.  $di/dt$

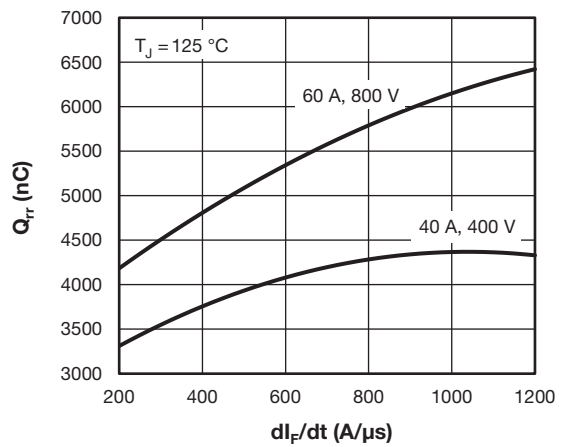


Fig. 7 - Typical Stored Charge vs.  $di/dt$

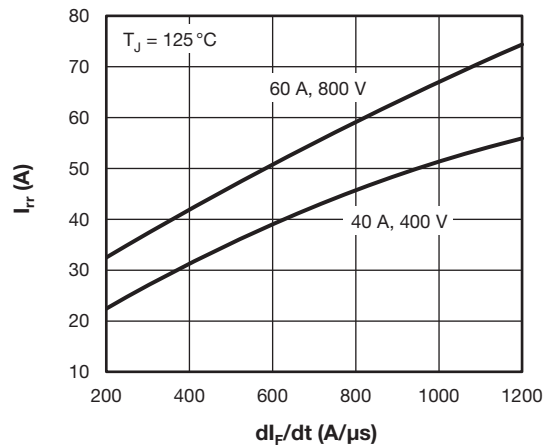
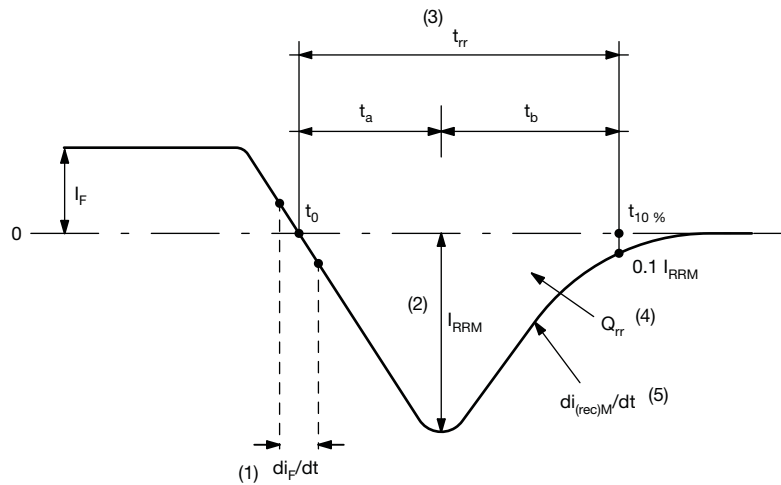

 Fig. 8 - Typical Recovery Current vs.  $di_F/dt$ 


Fig. 9 - Reverse Recovery Waveform and Definitions

**Notes**

- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from  $t_0$ , crossing point of negative going  $I_F$ , to point  $t_{10\%}$ ,  $0.1 I_{RRM}$
- (4)  $Q_{rr}$  - area under curve defined by  $t_0$  and  $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

- (5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

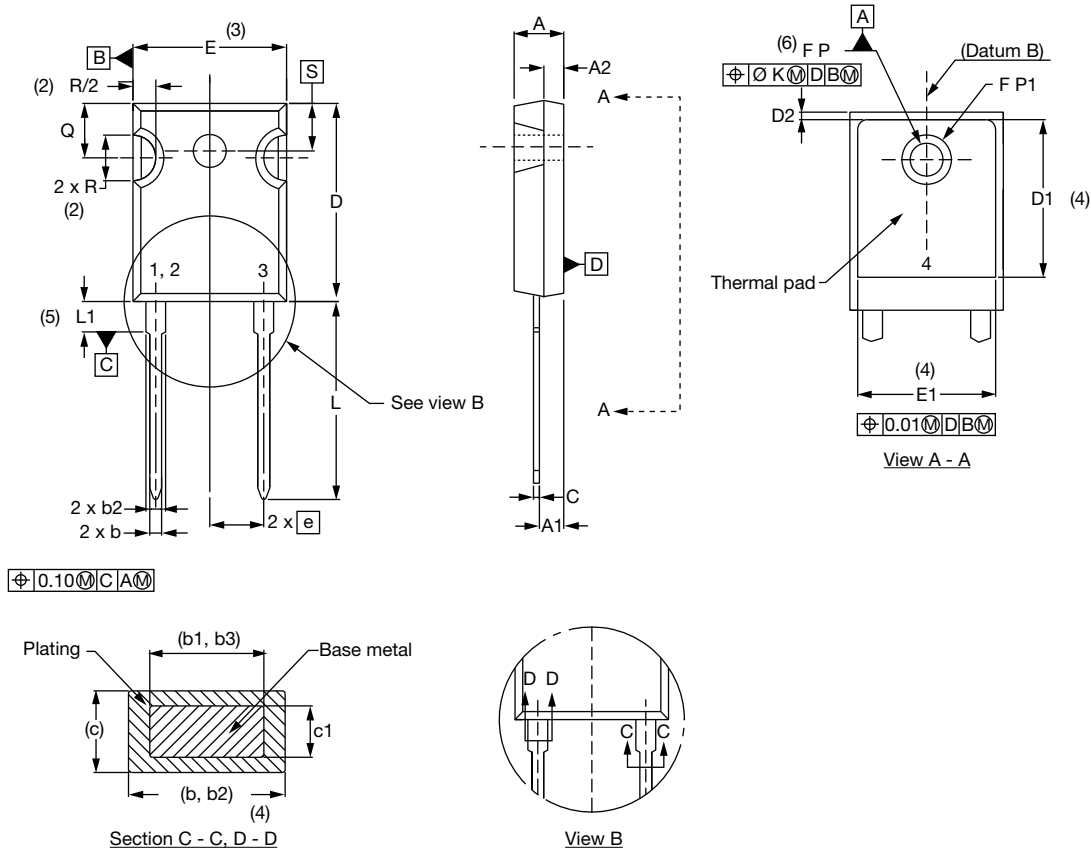
ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-E5PH6012L-N3	25	500	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95536">www.vishay.com/doc?95536</a>
Part marking information	<a href="http://www.vishay.com/doc?95648">www.vishay.com/doc?95648</a>



# TO-247AD 2L

**DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098		e	5.46 BSC		0.215 BSC		
b	0.99	1.40	0.039	0.055		Ø K	0.254		0.010		
b1	0.99	1.35	0.039	0.053		L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		Ø P	3.56	3.66	0.14	0.144	
c	0.38	0.89	0.015	0.035		Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51 BSC		0.217 BSC		
D2	0.51	1.35	0.020	0.053							

**Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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